2022 10 27

688396 2022

49.76

- 2022 10 26 2022
- 1 2022Q1-Q3 76.32 +10.17% 37.36% +1.94pct 20.57 +22.18% 18.62 +19.84%
- 2 2022Q3 24.86 / +0.54%/-5.54% 37.14% / -0.72pct/-1.25pct 7.03 / +14.14%/-4.28% 5.56 / +3.20%/-21.26%
- **“ IDM + ”** 2022Q3 24.86 / +0.54%/-5.54% 37.14% / -0.72pct/-1.25pct 7.03 / +14.14%/-4.28% 5.56 / +3.20%/-21.26%
- -100V 1500V MOSFET
- **12** 3 12 2021 26.2% 8 2022 MOSFET 8 IGBT GaN SiC
- “ IDM+ ” 2022-2024 25.32/30.41/35.66 25.27/29.72/34.41 EPS 1.91/2.25/2.61 “ ”
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2021 2022E 2023E 2024E 2021 2022E

TMT

2019

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